# Big picture

How have we been able to make cell phones more affordable while their functionality has exploded (cellular, WiFi, Bluetooth, GPS, computing, storage, digital camera, user-friendly interface)?

* Integration: how much functionality can be placed on a single chip (or how few components are left off-chip)
* Integration is due to (1) scaling of VLSI processes – CMOS technology – (2) innovations in RF architectures, circuits, devices.

These disciplines are all required, to some degree, for an RF designer:

* Communication theory
* Random signals
* Transceiver architectures
* IC design
* CAD tools
* Wireless standards
* Multiple access
* Signal propagation
* Microwave theory

RF design hexagon:

* Noise
* Power
* Frequency
* Gain
* Supply voltage
* Linearity
* … back to noise

Each metric trades off with its two adjacent metrics. For example, to lower the noise of a front-end amplifier, we must consume more power or sacrifice linearity.

Generic RF transceiver architecture:

* Receiver: antenna 🡪 LNA 🡪 downconverter (driven by oscillator, generated by frequency synthesizer) 🡪 ADC 🡪 digital baseband processor
* Transmitter: digital baseband processor 🡪 DAC 🡪 upconverter 🡪 PA 🡪 antenna

# Basic concepts

## Units

Voltage gain:

Power gain:

Voltage and power gain are equal in dB only if the input and output voltages appear across equal impedances. For example, the gain of an amplifier with an input resistance of and driving a load of is

and are rms values.

Powers are expressed in dBm:

For example, if we deliver a power of 0dBm across a 50Ohm load for a sinusoidal signal, what is the peak-to-peak voltage swing? 632mV.

Another example, a GSM receiver senses a narrowband modulated signal having a level of -100dBm. If the front-end amplifier has a voltage gain of 15dB, what is the peak-to-peak voltage swing at the amplifier output? 35.5uV.

We assumed that

* The input impedance of the front-end amplifier is 50Ohm
* A narrowband signal has roughly the same peak-to-average power relationship as a sinusoid

In most integrated RF systems, we prefer voltage quantities to power quantities since

* Input and output impedances of cascade stages may be unequal, so voltage gain and power gain are not equal
* Impedances may be largely capacitive or inductive, in which case there is no “real” (active) power

However, we still sometimes use dBm at interfaces that do not necessarily entail power transfer. If we drive a purely-capacitive load, the delivered average power is zero, but we can still calculate dBm as if we were driving a 50Ohm load with our voltage signal.